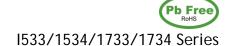


3.2 mm x 5.0 mm Ceramic Package SMD TCXO



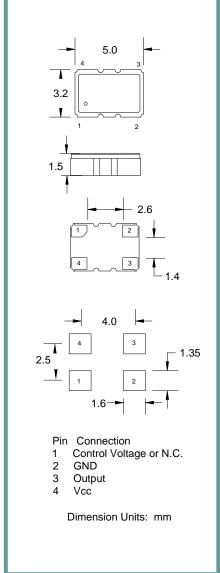
Product Features:

Low Jitter, Non-PLL Based Output Available in Both Clipped Sinewave and HCMOS Output Levels Compatible with Leadfree Processing

Applications:

Server & Storage Sonet /SDH 802.11 / Wifi T1/E1, T3/E3 Fibre Channel

Frequency	8.000 Mhz to 40 Mhz	
Output Level Clipped Sinewave HCMOS	0.8 V p-p Min. "0" = 0.1 Volts max '1'=2.64 Volts min or 80% of Vcc.	
Output Load Clipped Sinewave HCMOS	10K Ohms / 10 pF 15pF	
Duty Cycle (HCMOS)	50% ±10%	
Rise / Fall Time (HCMOS)	10 nS Max.	
Frequency Stability Vs Temperature Vs Voltage Vs Load(5%) Frequency Tolerance @	See Frequency Stability Table ± 0.3 ppm Max. ±.0.2 ppm Max. ± 1.0 ppm	
25° C	··	
Aging	± 1 ppm / Year Max.	
Supply Voltage	See Supply Voltage Table , tolerance ± 5%	
Current	2.0 mA Max. (Clipped Sinewave)	
	6.0 mA Max. (HCMOS)	
Voltage Control (I733/I734)	1.5 VDC ± 1.0 VDC, ± 5.0 ppm Min.	
Operating	See Operating Temperature Table	
Storage	-40° C to +85° C	
Phase Noise (typ. @ 20Mhz)	-86 dBc/Hz @ 10 Hz -115 dBc/Hz @ 100 Hz -138 dBc/Hz @ 1KHz -146 dBc/Hz @ 10 Khz	



Part Number Guide		Sample Part Number: I537-1Q3-20.000 Mhz		
Package	Operating Temperature	FrequencyStability vs Temperature	Supply Voltage	Frequency
I533 (Clipped Sinewave TCXO) I534 (HCMOS TCXO) I733 (Clipped Sinewave TCVCXO) I734 (HCMOS TCVCXO)	7 = 0° C to +50° C	**N = ±1.0 ppm	3 = 3.3 V	
	1 = 0° C to +70° C	**O = ±1.5 ppm	7 = 3.0 V	
	3 = -20° C to +70° C	**P = ±2.0 ppm	2 = 2.7 V	00 000 MIL-
	2 = -40° C to +85° C	Q = ±2.5 ppm		- 20.000 MHz
		$R = \pm 3.0 \text{ ppm}$		
		$J = \pm 5.0 \text{ ppm}$		

NOTE: A 0.01 µF bypass capacitor is recommended between Vcc (pin 4) and GND (pin 2) to minimize power supply noise.

** Not available for all temperature ranges.

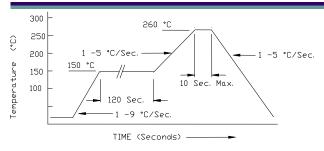
Pb Free

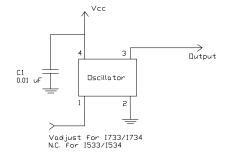


3.2 mm x 5.0 mm Ceramic Package SMD TCXO

Pb Free Solder Reflow Profile:

Typical Application:

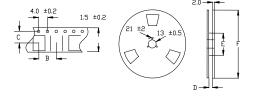




Package Information:

MSL = N.A. (package does not contain plastic, storage life is unlimited under normal room conditions). Termination = e4 (Au over Ni over W base metallization).

Tape and Reel Information:



Quantity per Reel	1000
Α	8 +/3
В	4 +/2
С	3.5 +/2
D	9 +/-1 or 12 +/-3
E	60 / 80
F	180

Environmental Specifications

Thermal Shock	MIL-STD-883, Method 1011, Condition A
	·
Moisture Resistance	MIL-STD-883, Method 1004
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Mechanical Vibration	MIL-STD-883, Method 2007, Condition A
Resistance to Soldering Heat	J-STD-020C, Table 5-2 Pb-free devices (except 2 cycles max)
Hazardous Substance	Pb-Free / RoHS / Green Compliant
Solderability	JESD22-B102-D Method 2 (Preconditioning E)
Terminal Strength	MIL-STD-883, Method 2004, Test Condition D
Gross Leak	MIL-STD-883, Method 1014, Condition C
Fine Leak	MIL-STD-883, Method 1014, Condition A2, R1=2x10-8 atm cc/s
Solvent Resistance	MIL-STD-202, Method 215

Marking

Line 1: I - Date Code (YWW)

Line 2: Frequency

^{*}Units are backward compatible with 240C reflow processes